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| SANYO | No.2085B | 2SB1203/2SD1803 |
| | | PNP/NPN Epitaxial Planar Silicon Transistors |
| High-Current Switching Applications | | |

Applications

- Relay drivers, high-speed inverters, converters, and other general high-current switching applications

Features

- Low collector-to-emitter saturation voltage
- High current and high f_T
- Excellent linearity of h_{FE}
- Fast switching time
- Small and slim package making it easy to make 2SB1203/2SD1803-applied sets smaller

() : 2SB1203

Absolute Maximum Ratings at $T_a = 25^\circ\text{C}$

| | | | unit |
|------------------------------|-----------|--------------------------|------------------------------|
| Collector to Base Voltage | V_{CBO} | (-) | 60 V |
| Collector to Emitter Voltage | V_{CEO} | (-) | 50 V |
| Emitter to Base Voltage | V_{EBO} | (-) | 6 V |
| Collector Current | I_C | (-) | 5 A |
| Collector Current(Pulse) | I_{CP} | (-) | 8 A |
| Collector Dissipation | P_C | | 1 W |
| | | $T_c = 25^\circ\text{C}$ | 20 W |
| Junction Temperature | T_j | | 150 $^\circ\text{C}$ |
| Storage Temperature | T_{stg} | | -55 to +150 $^\circ\text{C}$ |

Electrical Characteristics at $T_a = 25^\circ\text{C}$

| | | | min | typ | max | unit |
|--------------------------|-------------|---|-----|-------|------|-----------------|
| Collector Cutoff Current | I_{CBO} | $V_{CB} = (-)40\text{V}, I_E = 0$ | | | (-) | 1 μA |
| Emitter Cutoff Current | I_{EBO} | $V_{EB} = (-)4\text{V}, I_C = 0$ | | | (-) | 1 μA |
| DC Current Gain | $h_{FE(1)}$ | $V_{CE} = (-)2\text{V}, I_C = (-)0.5\text{A}$ | 70* | | 400* | |
| | $h_{FE(2)}$ | $V_{CE} = (-)2\text{V}, I_C = (-)4\text{A}$ | 35 | | | |
| Gain-Bandwidth Product | f_T | $V_{CE} = (-)5\text{V}, I_C = (-)1\text{A}$ | | (130) | | MHz |
| | | | | 180 | | MHz |
| Output Capacitance | C_{ob} | $V_{CE} = (-)10\text{V}, f = 1\text{MHz}$ | | (60) | | pF |
| | | | | 40 | | pF |

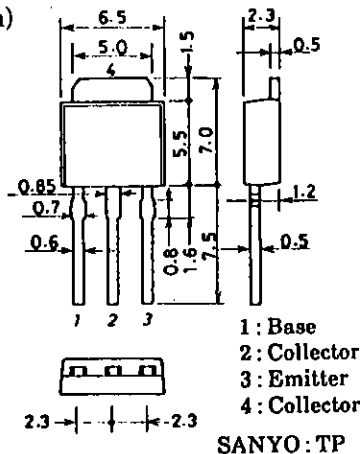
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* : The 2SB1203/2SD1803 are classified by 0.5A h_{FE} as follows :

| | | | | | | | | | | | |
|----|---|-----|-----|---|-----|-----|---|-----|-----|---|-----|
| 70 | Q | 140 | 100 | R | 200 | 140 | S | 280 | 200 | T | 400 |
|----|---|-----|-----|---|-----|-----|---|-----|-----|---|-----|

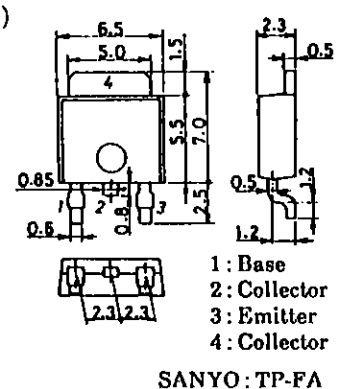
Package Dimensions 2045B

(unit : mm)



Package Dimensions 2044B

(unit : mm)

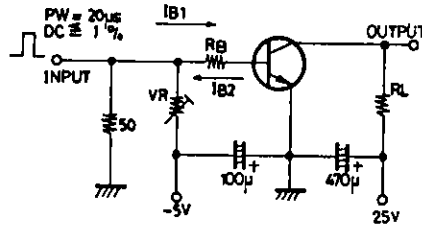


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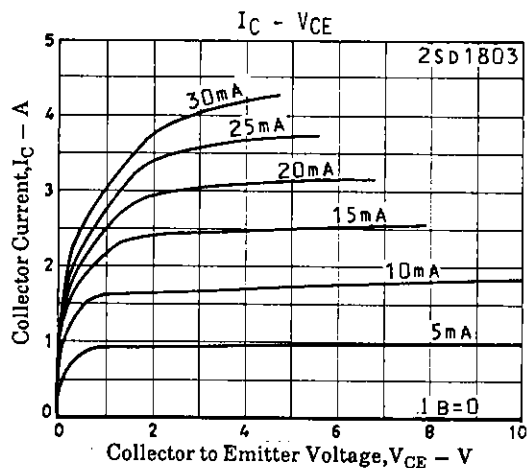
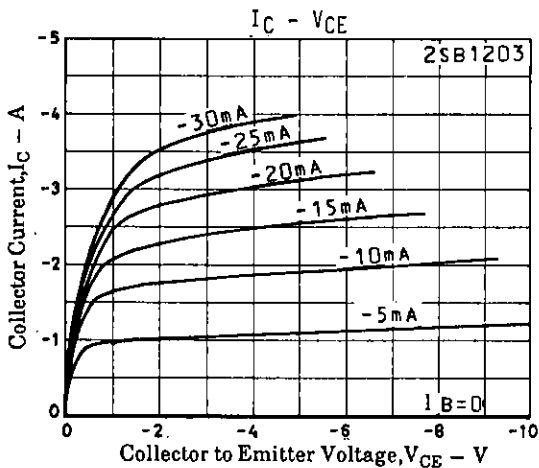
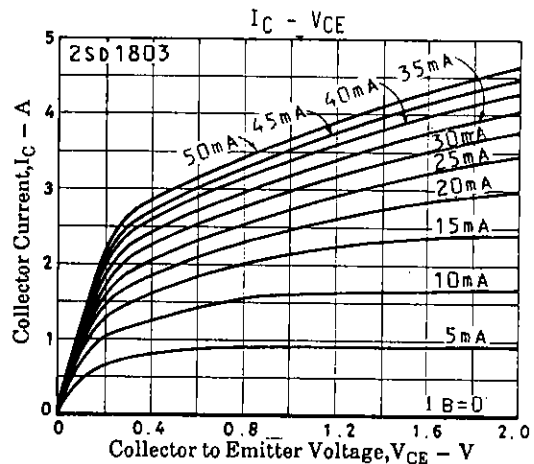
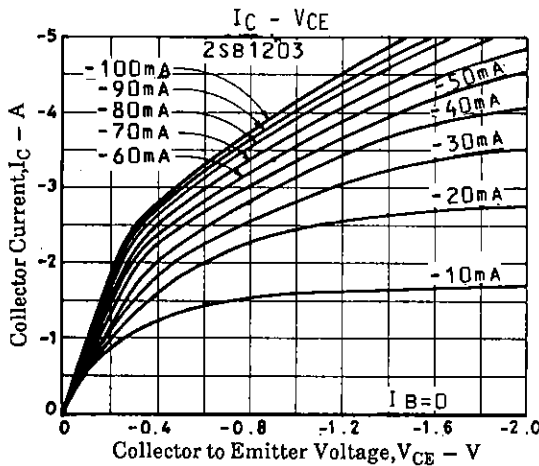
| | | | min | typ | max | unit |
|------------------------|---------------|---------------------------------|-------|--------|--------|------|
| C-E Saturation Voltage | $V_{CE(sat)}$ | $I_C = (-)3A, I_B = (-)0.15A$ | | (-280) | (-550) | mV |
| B-E Saturation Voltage | $V_{BE(sat)}$ | $I_C = (-)3A, I_B = (-)0.15A$ | | 220 | 400 | mV |
| C-B Breakdown Voltage | $V_{(BR)CBO}$ | $I_C = (-)10\mu A, I_E = 0$ | (-60) | | | V |
| C-E Breakdown Voltage | $V_{(BR)CEO}$ | $I_C = (-)1mA, R_{BE} = \infty$ | (-50) | | | V |
| E-B Breakdown Voltage | $V_{(BR)EBO}$ | $I_E = (-)10\mu A, I_C = 0$ | (-6) | | | V |
| Turn-on Time | t_{on} | See specified Test Circuit. | | (50) | | ns |
| | | | | 50 | | ns |
| Storage Time | t_{stg} | | | (450) | | ns |
| | | | | 500 | | ns |
| Fall Time | t_f | | | (20) | | ns |
| | | | | 20 | | ns |

Switching Time Test Circuit

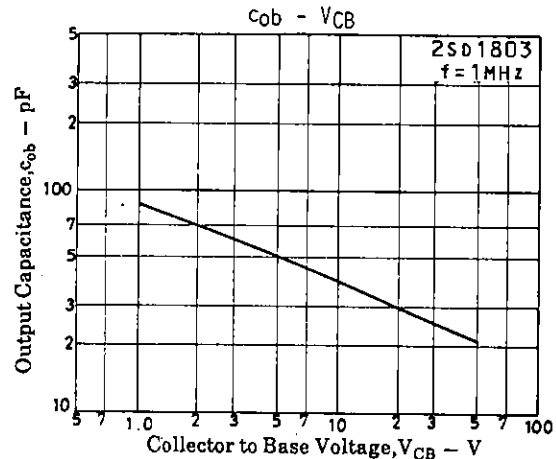
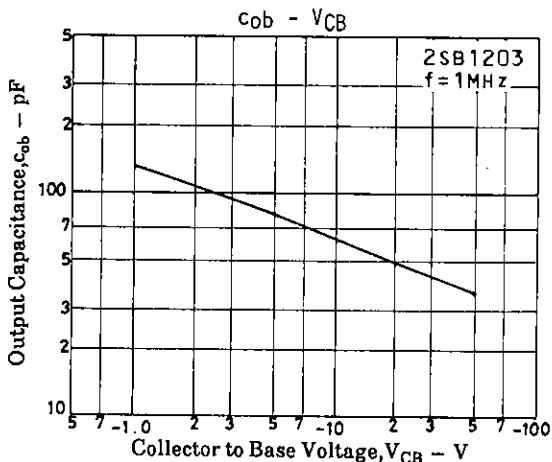
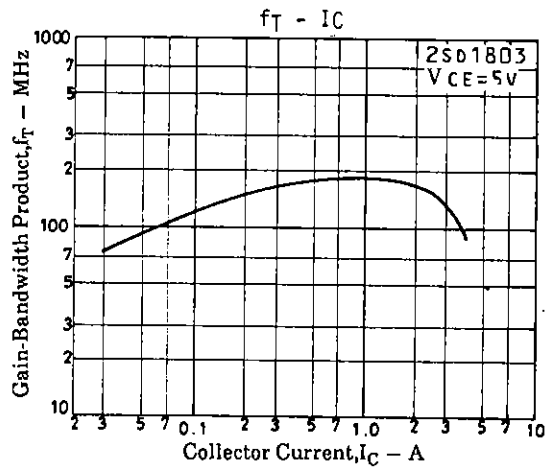
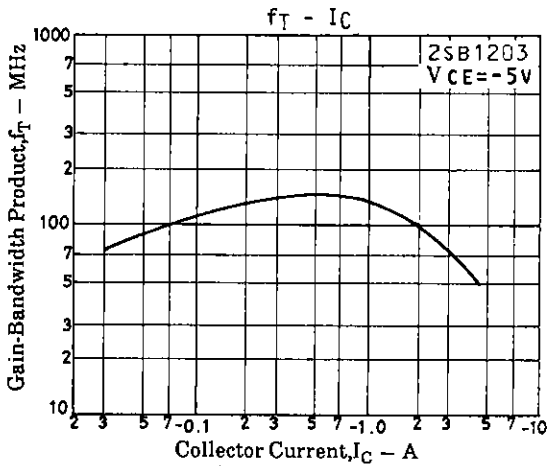
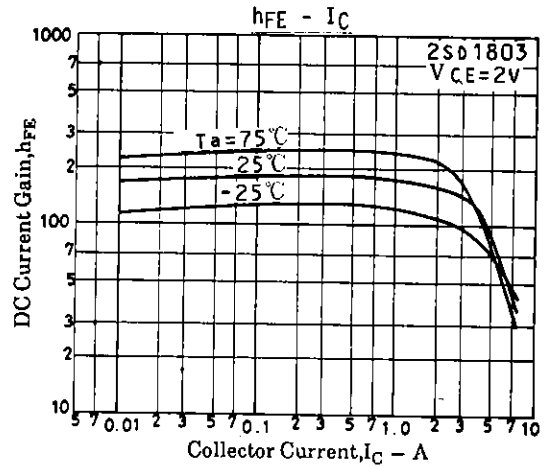
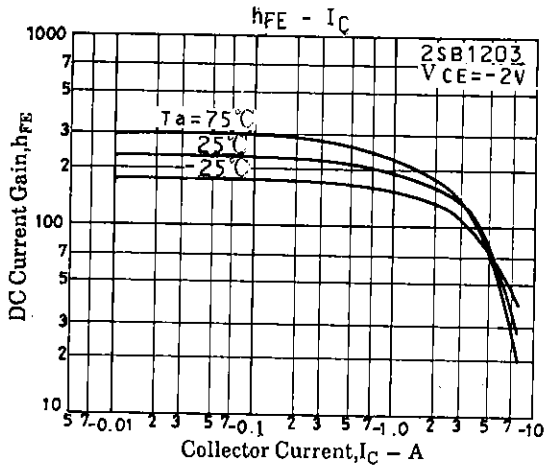
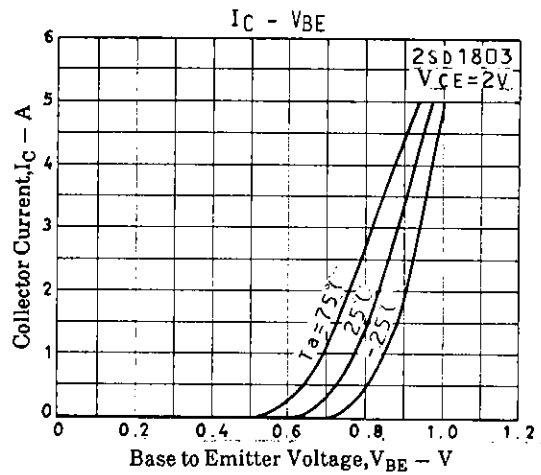
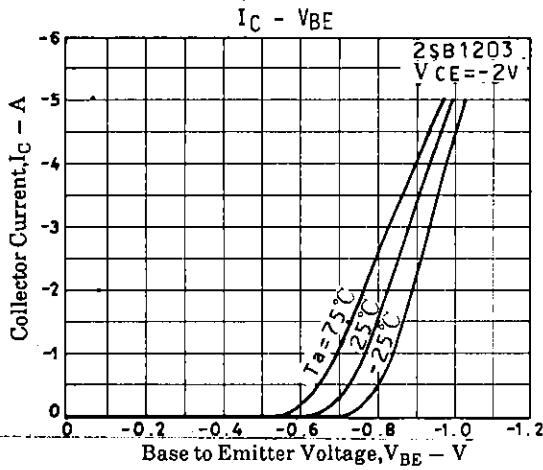


$I_C = 10, I_{B1} = -10, I_{B2} = 2A$
(For PNP, the polarity is reversed.)

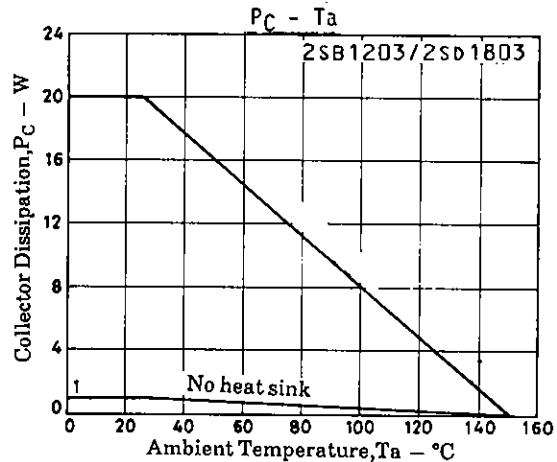
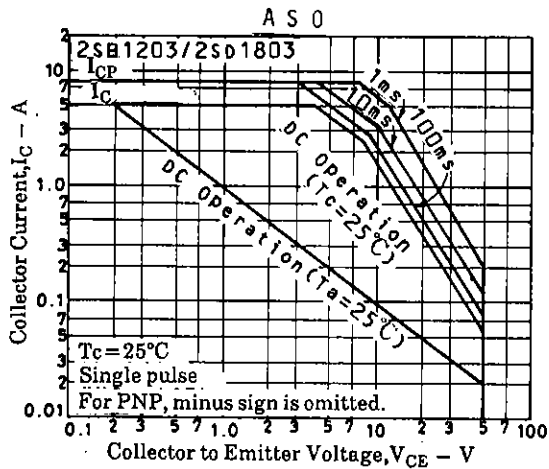
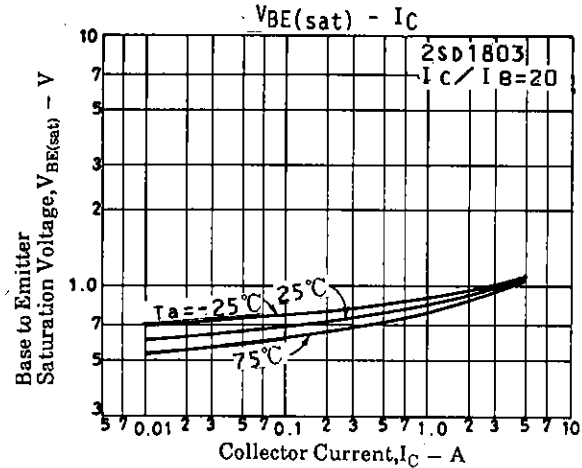
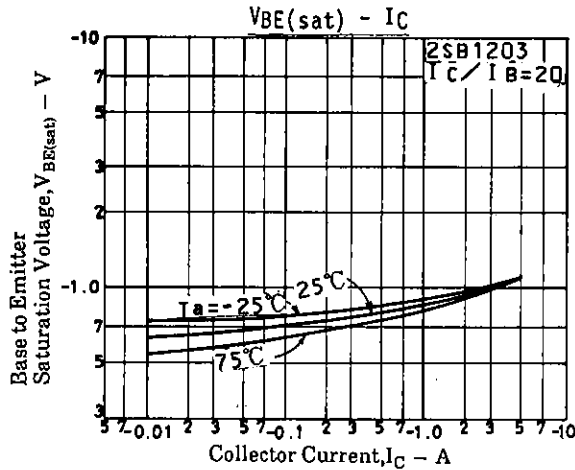
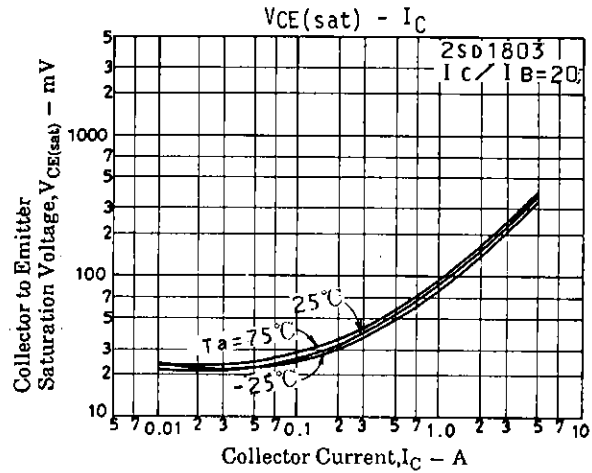
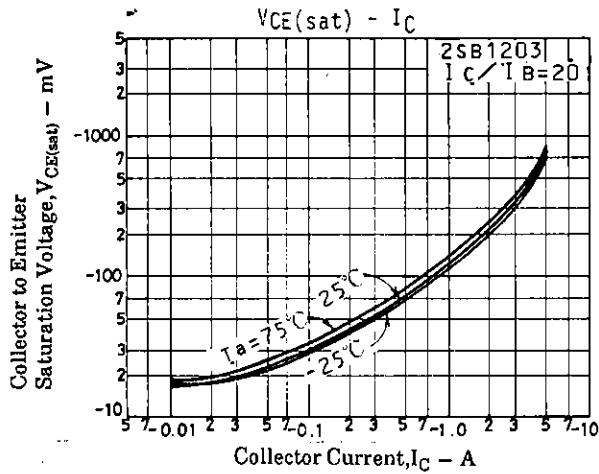
Unit (Resistance : Ω , Capacitance : F)



2SB1203/2SD1803



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